IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of:

Wu et al

No.:

09/903,415

FEB 0 7 2002

July 11, 2001

Group No.: 1731

Examiner: Unknown

THE HASE

Docket No. LIGHT2140

For: METHOD OF FORMING AN OPTICAL COMPONENT

CERTIFICATION UNDER 37 CFR § 1.8

I hereby certify that the documents referred to as enclosed herein are being deposited with the United States Postal Service as first class mail on this date ______________________________, in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231

Signature

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

INFORMATION DISCLOSURE STATEMENT

Applicant hereby cites the documents listed in accompany Form PTO-1449 with respect to the above-referenced patent application under the provisions of 37 CFR 1.97(b). Copies of the documents are attached.

The Examiner is respectfully requested to make the listed documents of record in connection with the prosecution of the subject application.

Respectfully submitted,

Date: 24 January 2002

TERRANCE A. MEADOR Attorney for Applicant(s) Registration No. 30,298

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¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two letter-code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard St. 16 if possible. ⁶Applicant is to place a check mark here if English language translation is attached.

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Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	Т
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